BCP68; BC868; BC68PA 20 V, 2 A NPN medium power transistors Rev. 8 – 18 October 2011

1. Product profile

1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product overview

Type number ^[1]	Package	Package				
	NXP	JEITA	JEDEC			
BCP68	SOT223	SC-73	-	BCP69		
BC868	SOT89	SC-62	TO-243	BC869		
BC68PA	SOT1061	-	-	BC69PA		

[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Two current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	20	V
I _C	collector current		-	-	2	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	3	А



20 V, 2 A NPN medium power transistors

Table 2.	Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FE}	DC current gain	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<mark>[1]</mark> 85	-	375	
	h _{FE} selection -25	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<u>1</u> 160	-	375	

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2, 4
3	emitter		1-
4	collector		3
SOT89			sym016
1	emitter		
2	collector		2 J
3	base		3
SOT1061			
1	base		2
2	emitter	3	3
3	collector		
		1 2 Transparent top view	sym021

20 V, 2 A NPN medium power transistors

3. Ordering information

Table 4. Ordering information						
Type number ^[1]	Package					
	Name	Description	Version			
BCP68	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BC868	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89			
BC68PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061			

[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes	
Type number	Marking code
BCP68	BCP68
BCP68-25	BCP68/25
BC868	CAC
BC868-25	CDC
BC68PA	AR
BC68-25PA	AS

BCP68_BC868_BC68PA

20 V, 2 A NPN medium power transistors

5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	32	V
V _{CEO}	collector-emitter voltage	open base	-	20	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	2	А
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	3	A
I _B	base current		-	0.4	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	0.4	A
P _{tot}	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$			
	BCP68		<u>[1]</u> -	0.65	W
			[2] _	1.00	W
			[3] _	1.35	W
	BC868		<u>[1]</u> _	0.50	W
			[2] _	0.95	W
			<u>[3]</u>	1.35	W
	BC68PA		<u>[1]</u> _	0.42	W
			[2] _	0.83	W
			<u>[3]</u> _	1.10	W
			<u>[4]</u> _	0.81	W
			<u>[5]</u> _	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

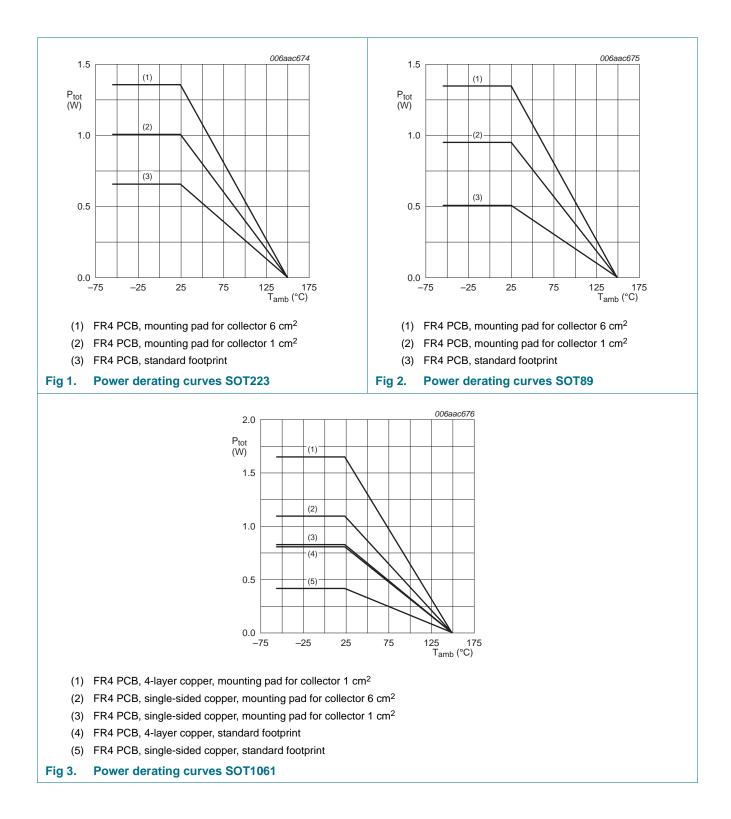
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



20 V, 2 A NPN medium power transistors

6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
-				IVIIII	тур	IVIAX	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air					
	BCP68		<u>[1]</u>	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
	BC868		[1]	-	-	250	K/W
			[2]	-	-	132	K/W
			[3]	-	-	93	K/W
	BC68PA		[1]	-	-	298	K/W
			[2]	-	-	151	K/W
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point						
	BCP68			-	-	16	K/W
	BC868			-	-	16	K/W
	BC68PA			-	-	20	K/W

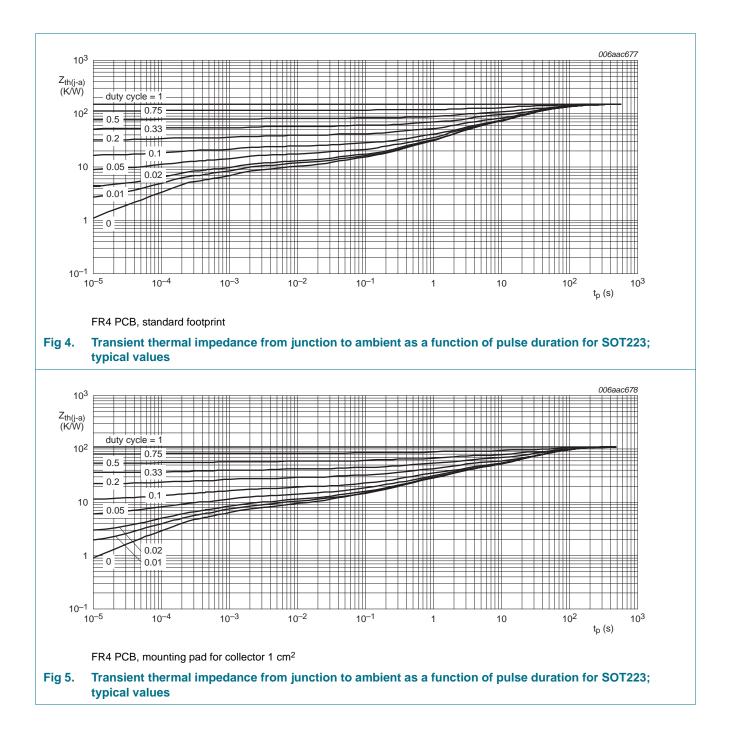
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

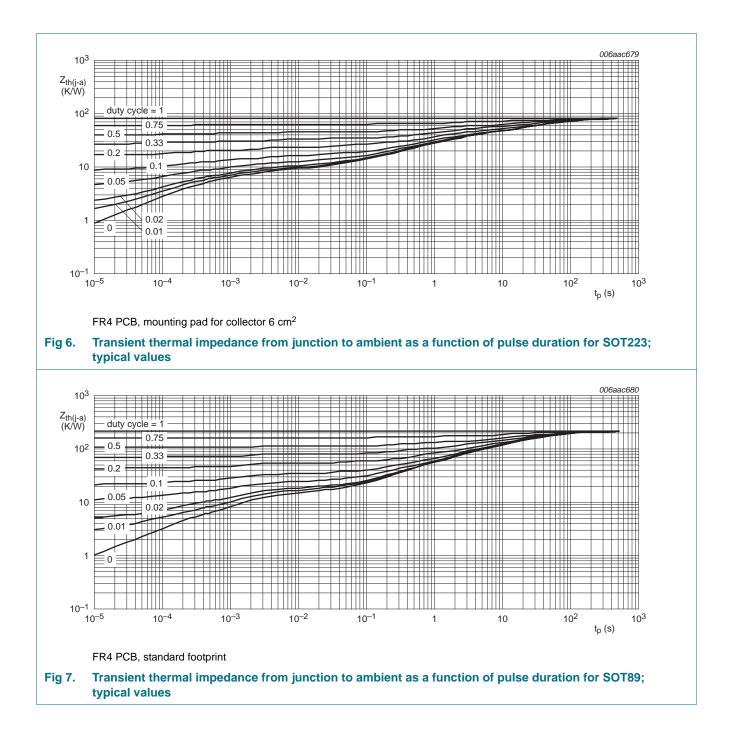
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

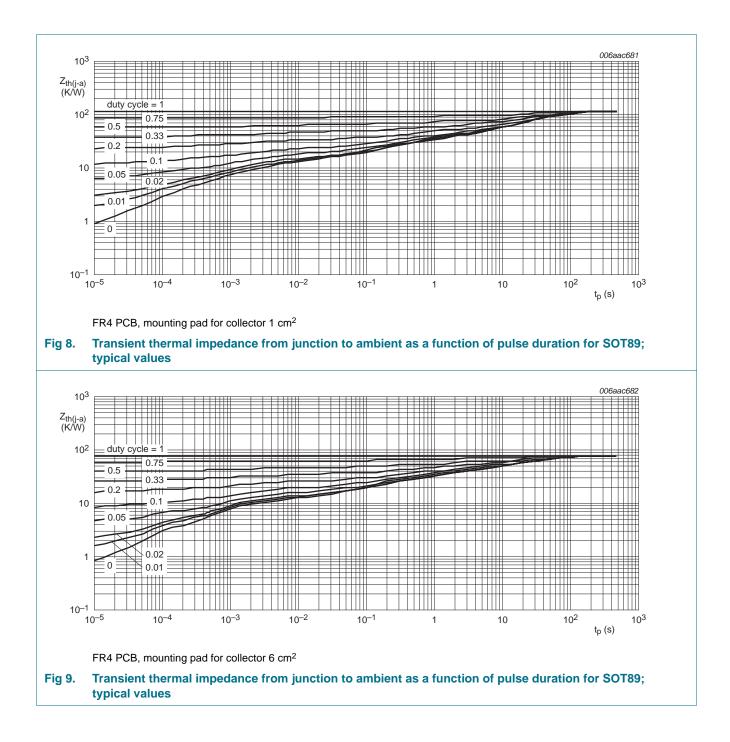
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

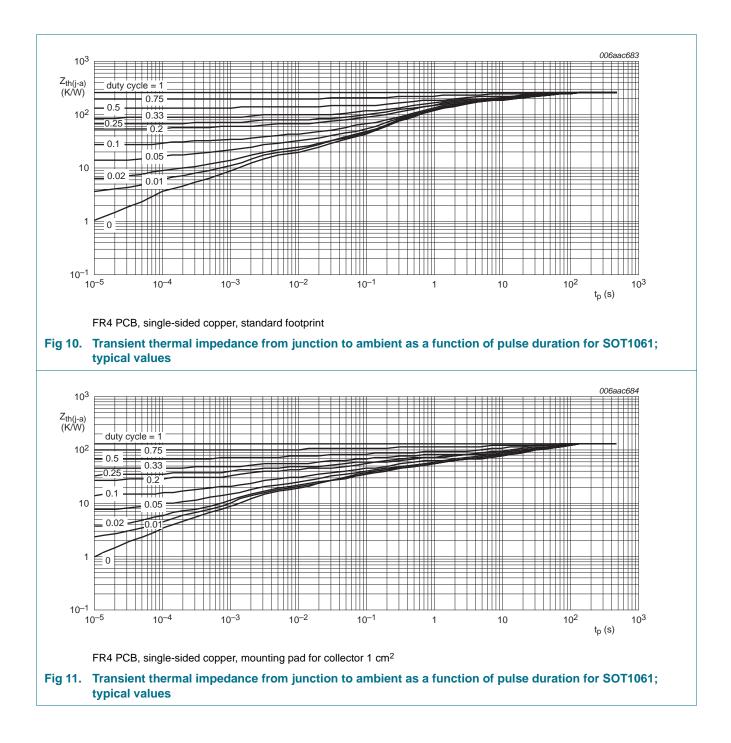
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

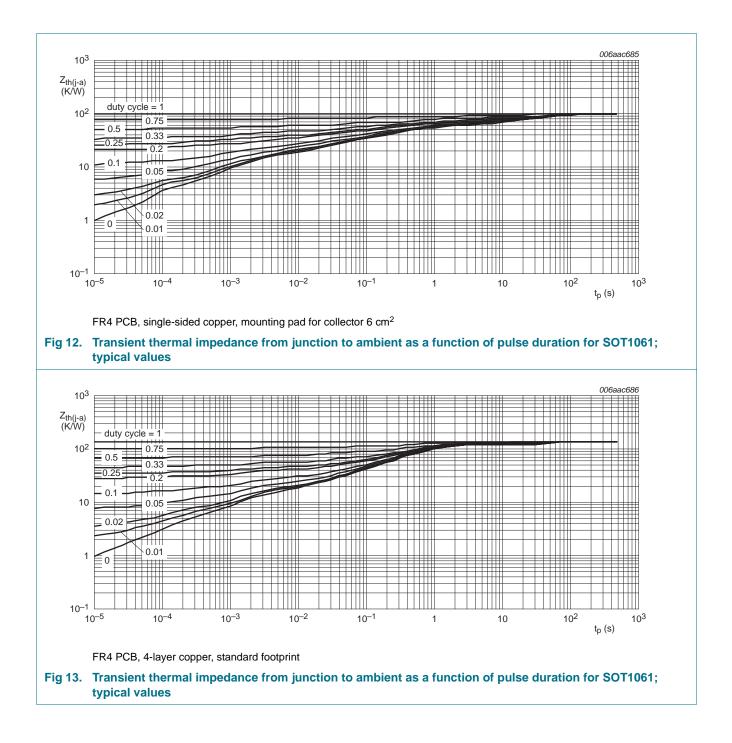
[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

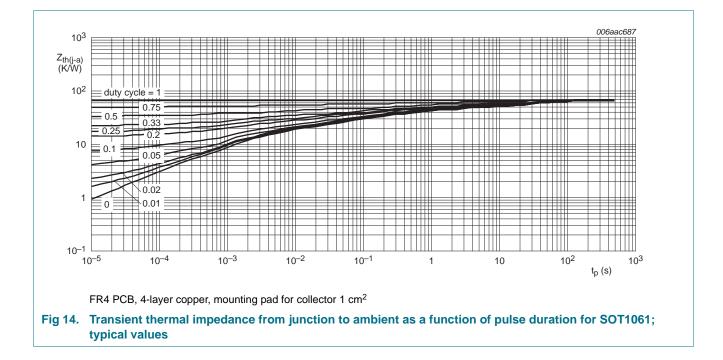










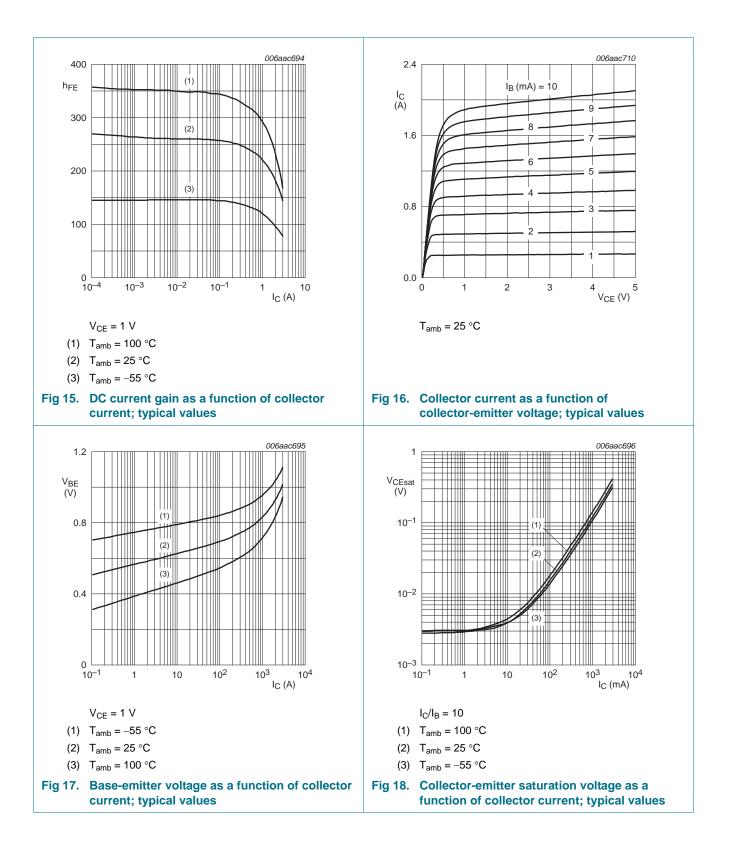


20 V, 2 A NPN medium power transistors

7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = 25 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 25 \text{ V}; \text{ I}_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V					
		I _C = 5 mA		50	-	-	
	DC current gain	$V_{CE} = 1 V$					
		I _C = 500 mA	[1]	85	-	375	
		$I_{\rm C} = 1 \rm A$	[1]	60	-	-	
		I _C = 2 A	[1]	40	-	-	
	DC current gain	$V_{CE} = 1 V$					
	h _{FE} selection -25	I _C = 500 mA	[1]	160	-	375	
V _{CEsat}	collector-emitter	I _C = 1 A; I _B = 100 mA	[1]	-	-	0.5	V
	saturation voltage	$I_{C} = 2 \text{ A}; I_{B} = 200 \text{ mA}$	[1]	-	-	0.6	V
V _{BE}	base-emitter voltage	V_{CE} = 10 V; I_{C} = 5 mA	<u>[1]</u>	-	-	0.7	V
		$V_{CE} = 1 V; I_{C} = 1 A$	[1]	-	-	1	V
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	22	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz		40	170	-	MHz

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta = 0.02$.



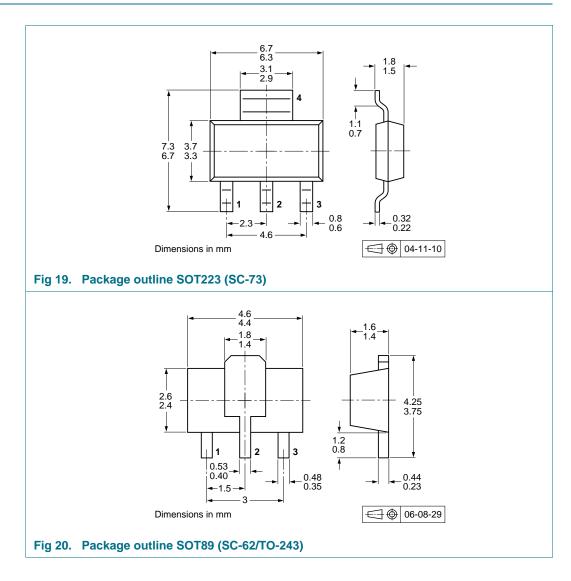
20 V, 2 A NPN medium power transistors

8. Test information

8.1 Quality information

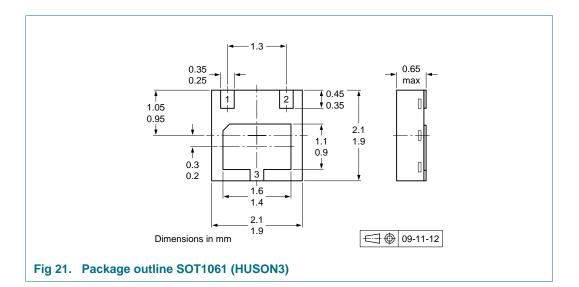
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



BCP68_BC868_BC68PA

20 V, 2 A NPN medium power transistors



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

BCP68 SOT223 8 mm pitch, 12 mm tape and reel -11513	Туре	Package	Description	Description		Packing quantity		
BC868 SOT89 8 mm pitch, 12 mm tape and reel; T1 [3] -115 - -13 8 mm pitch, 12 mm tape and reel; T3 [4] -146 - -	number ^[2]				1000	3000	4000	
8 mm pitch, 12 mm tape and reel; T3 [4] -146	BCP68	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135	
- · · · · · · · · · · · · · · · · · · ·	BC868	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135	
BC68PA SOT1061 4 mm pitch, 8 mm tape and reel115 -			8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-	
	BC68PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-	

[1] For further information and the availability of packing methods, see Section 14.

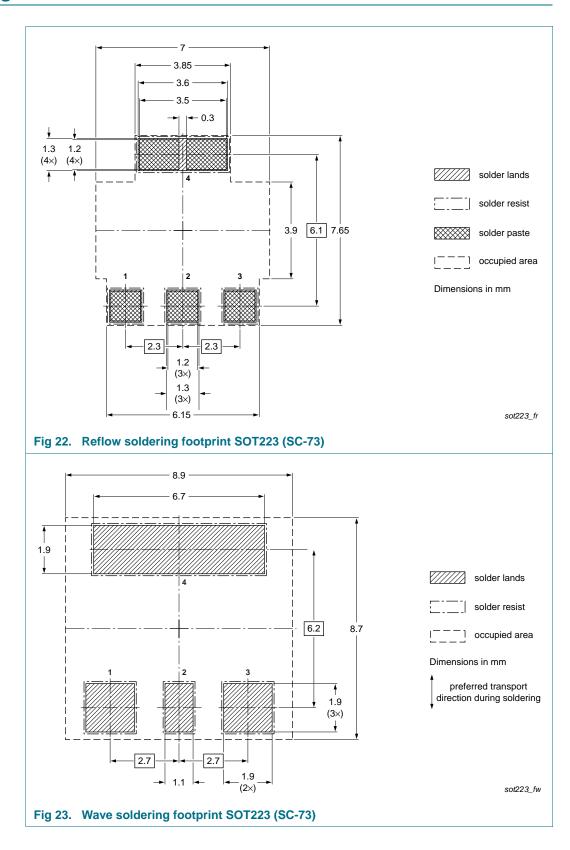
[2] Valid for all available selection groups.

[3] T1: normal taping

[4] T3: 90° rotated taping

20 V, 2 A NPN medium power transistors

11. Soldering



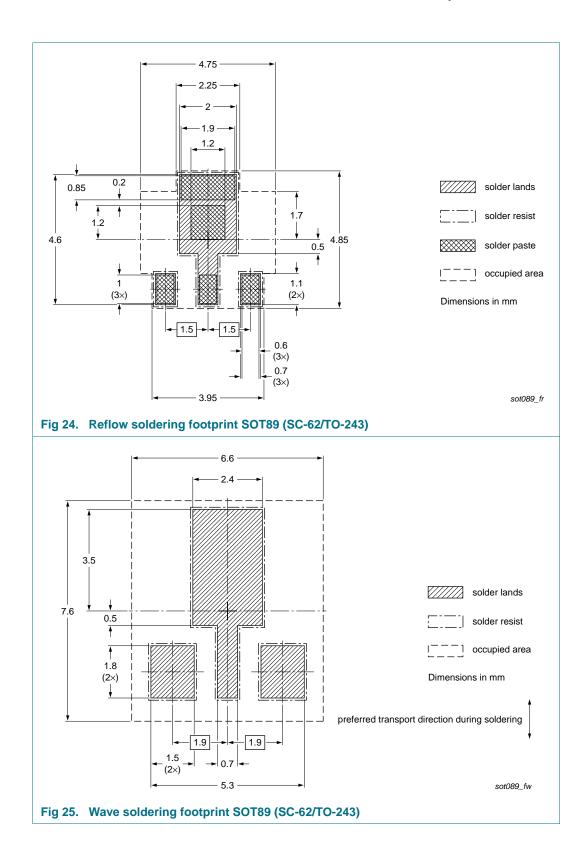
BCP68_BC868_BC68PA

© NXP B.V. 2011. All rights reserved

Product data sheet

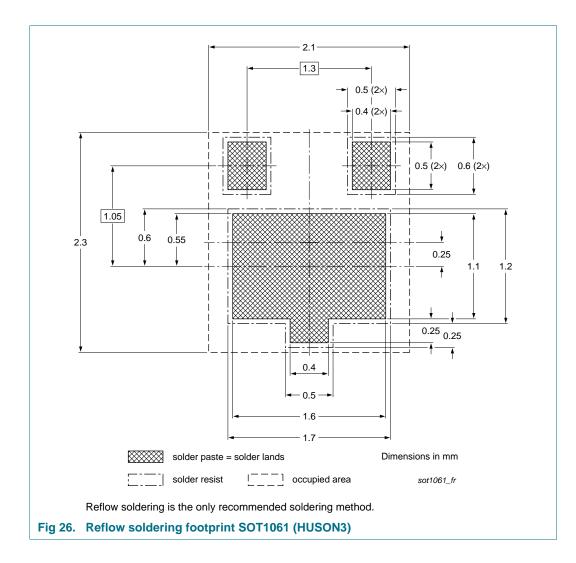
17 of 23

20 V, 2 A NPN medium power transistors



© NXP B.V. 2011. All rights reserved.

20 V, 2 A NPN medium power transistors



BCP68_BC868_BC68PA

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP68_BC868_BC68PA v.8	20111018	Product data sheet	-	BC868 v.7 BCP68 v.4		
Modifications:		of this document has be of NXP Semiconductors.	en redesigned to comp	bly with the new identity		
	 Legal texts 	have been adapted to th	e new company name	where appropriate.		
	 Type numb 	er BC68PA added				
	Section 1 "	Product profile": updated				
	Section 2 "	Pinning information": upd	ated			
	 Section 3 " 	Ordering information": up	dated			
	 Section 4 " 	Marking": updated				
	 Section 8 " 	Test information": added				
	 <u>Section 9 "Package outline"</u>: updated 					
	 <u>Section 10 "Packing information"</u>: added 					
	Section 11	"Soldering": added				
	• <u>Table 6, 7</u> a	and <u>8</u> : updated according	to latest measuremen	nts		
	 Figure 1, 2 	, <u>6</u> , <u>8</u> , <u>15</u> to <u>18</u> : updated				
	• Figure 3, 4	, <u>5</u> , <u>7</u> , <u>9</u> , <u>10</u> to <u>13</u> : added				
BC868 v.7	20041108	Product specification	-	BC868 v.6		
BC868 v.6	20031202	Product specification	-	BC868 v.5		
BC868 v.5	19990408	Product specification	-	BC868 v.4		
BC868 v.4	19980716	Product specification	-	BC868_CNV v.3		
BC868_CNV v.3	19970319	Product specification	-	BC868_CNV v.2		
BC868_CNV v.2	19970307	Product specification	-	-		
BCP68 v.4	20031125	Product specification	-	BCP68 v.3		
BCP68 v.3	19990408	Product specification	-	BCP68_CNV v.2		
BCP68_CNV v.2	19970409	Product specification				

20 V, 2 A NPN medium power transistors

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors products product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

BCP68_BC868_BC68PA

All information provided in this document is subject to legal disclaimers.

20 V, 2 A NPN medium power transistors

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

20 V, 2 A NPN medium power transistors

15. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 3
4	Marking 3
5	Limiting values 4
6	Thermal characteristics 6
7	Characteristics 13
8	Test information 15
8.1	Quality information 15
9	Package outline 15
10	Packing information 16
11	Soldering 17
12	Revision history 20
13	Legal information 21
13.1	Data sheet status 21
13.2	Definitions 21
13.3	Disclaimers
13.4	Trademarks 22
14	Contact information 22
15	Contents 23

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2011.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com Date of release: 18 October 2011

Document identifier: BCP68_BC868_BC68PA

All rights reserved.